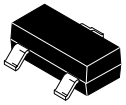
# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

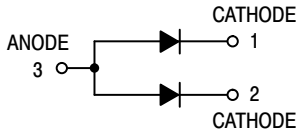
# Monolithic Dual Switching Diodes

**ON Semiconductor®**

**http://onsemi.com**



**SOT−23 (TO−236AB)**
**CASE 318−08**
**STYLE 12**




### Features

- AEC−Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant*

### MAXIMUM RATINGS (EACH DIODE)

| Rating | Symbol | Value | Unit |
|---|---|---|---|
| Reverse Voltage<br>MMBD2835LT1G, SMMBD2835LT1G<br>MMBD2836LT1G | $V_R$ | <br>35<br>75 | Vdc |
| Forward Current | $I_F$ | 100 | mAdc |

### THERMAL CHARACTERISTICS

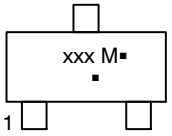
| | | | |
|---|---|---|---|
| Total Device Dissipation FR−5 Board (Note 1)<br>$T_A$ = 25°C<br>Derate above 25°C | $P_D$ | 225<br><br>1.8 | mW<br><br>mW/°C |
| Thermal Resistance, Junction−to−Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 2)<br>$T_A$ = 25°C<br>Derate above 25°C | $P_D$ | 300<br><br>2.4 | mW<br><br>mW/°C |
| Thermal Resistance, Junction−to−Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | $T_J$, $T_{stg}$ | −55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR−5 = 1.0 × 0.75 × 0.062 in.
2. Alumina = 0.4 × 0.3 × 0.024 in. 99.5% alumina.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### MARKING DIAGRAM




xxx = Specific Device Code
A3X = MMBD2835LT1G
SMMBD2835LT1G
A2X = MMBD2836LT1G
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### ORDERING INFORMATION

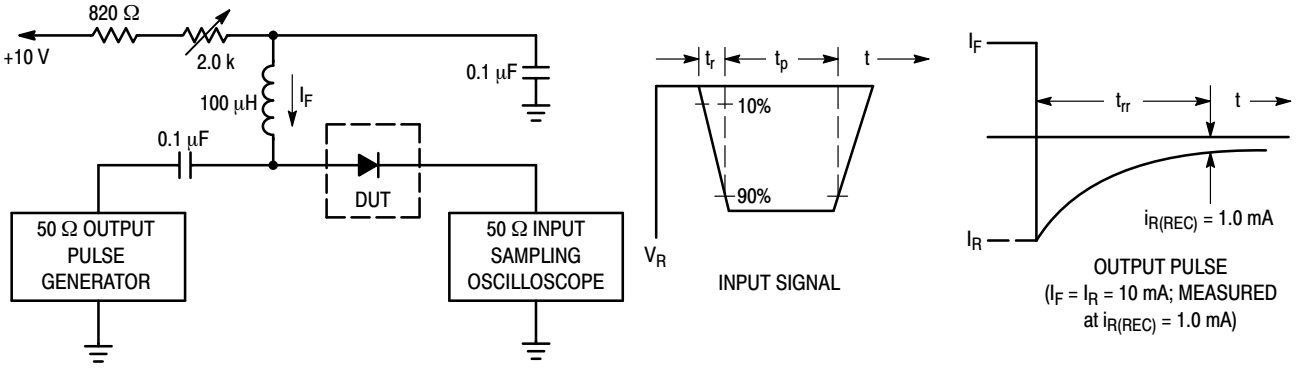
| Device | Package | Shipping† |
|---|---|---|
| MMBD2835LT1G | SOT−23 (Pb−Free) | 3,000 / Tape & Reel |
| SMMBD2835LT1G | SOT−23 (Pb−Free) | 3,000 / Tape & Reel |
| MMBD2836LT1G | SOT−23 (Pb−Free) | 3,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**ELECTRICAL CHARACTERISTICS** ($T_A$ = 25°C unless otherwise noted) **(EACH DIODE)**

| Characteristic | Symbol | Min | Max | Unit |
|---|---|---|---|---|
| **OFF CHARACTERISTICS** | | | | |
| Reverse Breakdown Voltage ($I_R$ = 100 μAdc)<br>MMBD2835LT1G, SMMBD2835LT1G<br>MMBD2836LT1G | $V_{(BR)}$ | <br>35<br>75 | <br>–<br>– | Vdc |
| Reverse Voltage Leakage Current (Note 3)<br>($V_R$ = 30 Vdc)<br>MMBD2835LT1G, SMMBD2835LT1G<br>($V_R$ = 50 Vdc)<br>MMBD2836LT1G | $I_R$ | <br><br>–<br><br>– | <br><br>100<br><br>100 | nAdc |
| Diode Capacitance ($V_R$ = 0 V, f = 1.0 MHz) | $C_T$ | – | 4.0 | pF |
| Forward Voltage<br>($I_F$ = 10 mAdc)<br>($I_F$ = 50 mAdc)<br>($I_F$ = 100 mAdc) | $V_F$ | <br>–<br>–<br>– | <br>1.0<br>1.0<br>1.2 | Vdc |
| Reverse Recovery Time ($I_F$ = $I_R$ = 10 mAdc, $I_{R(REC)}$ = 1.0 mAdc) (Figure 1) | $t_{rr}$ | – | 4.0 | ns |

3. For each individual diode while the second diode is unbiased.




Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ($I_F$) of 10 mA.
2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
3. $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

## CURVES APPLICABLE TO EACH CATHODE

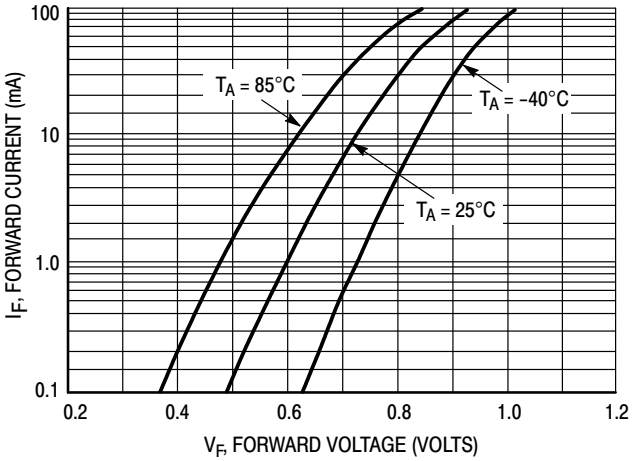



**Figure 2. Forward Voltage**

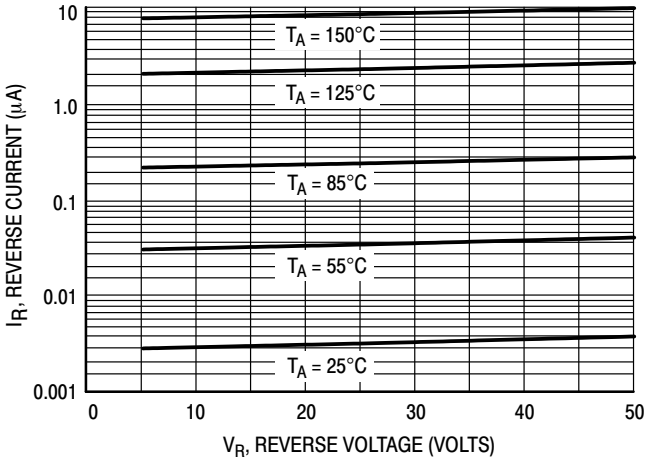



**Figure 3. Leakage Current**

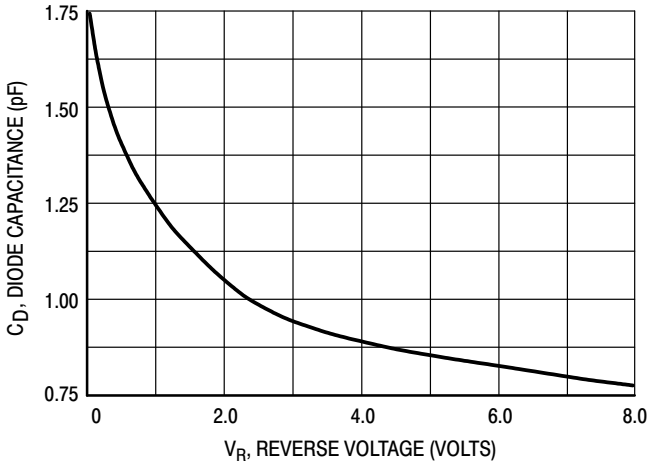
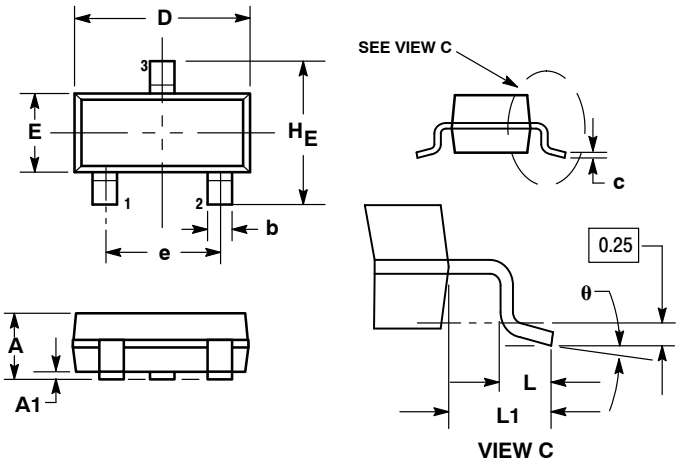



**Figure 4. Capacitance**

## PACKAGE DIMENSIONS

**SOT−23 (TO−236)**
CASE 318−08
ISSUE AP

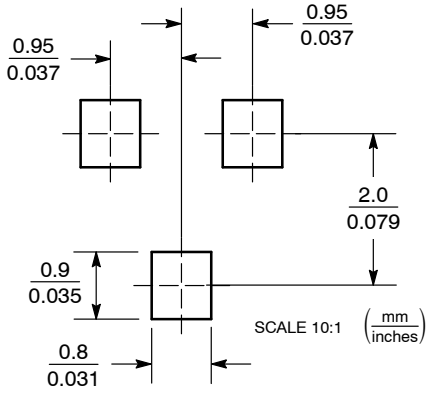



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | INCHES | | |
|---|---|---|---|---|---|---|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.040 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.018 | 0.020 |
| c | 0.09 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.081 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.029 |
| $H_E$ | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| θ | 0° | −−− | 10° | 0° | −−− | 10° |

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

## SOLDERING FOOTPRINT



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**MMBD2835LT1/D**

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